



Attorney's Docket No. 5308-156

284477  
PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE  
In re: Ryu et al.  
Serial No.: 09/911,995  
Filed: July 24, 2001

Group Art Unit: 2811  
Confirmation No.: 5240

For: SILICON CARBIDE POWER METAL-OXIDE SEMICONDUCTOR FIELD  
EFFECT TRANSISTORS HAVING A SHORTING CHANNEL AND  
METHODS OF FABRICATING SILICON CARBIDE METAL-OXIDE  
SEMICONDUCTOR FIELD EFFECT TRANSISTORS HAVING A  
SHORTING CHANNEL

Commissioner for Patents  
Washington, DC 20231

Date: October 21, 2002

**SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT**

Sir:

Attached is a list of documents on form PTO-1449 together with copies of each identified document. This Information Disclosure Statement is submitted in accordance with 37 C.F.R. § 1.97(c), before final Office Action or Allowance, whichever is earlier.

Please charge Deposit Account No. 50-0220 in the amount of \$180.00 for the fee specified in 37 C.F.R. § 1.17(p). The Commissioner is authorized to charge any additional fee or credit any refund to Deposit Account No. 50-0220.

Respectfully submitted,

Timothy J. O'Sullivan  
Registration No. 35,632

Customer Number:



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PATENT TRADEMARK OFFICE

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner for Patents, Washington, DC 20231, on October 21, 2002.  
Traci A. Brown

Date of Signature: October 21, 2002

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